# NSN 5961-01-545-8609

Transistor - Page 1 of 1

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## **Inclosure Material:**

Metal

# **Overall Height:**

Between 0.670 inches and 0.710 inches

# **Overall Diameter:**

Between 0.209 inches and 0.230 inches

## **End Application:**

Circuit card assembly

## **Features Provided:**

Electrostatic sensitive

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter voltage, dc

## Current Rating Per Characteristic:

50.00 milliamperes all primaries

# Power Rating Per Characteristic:

1.2 milliwatts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Product Name:**

(inavy)semiconductor devic (drawing)semiconductor device, transistor, amplifier, pnp, silicon(a3263509)

#### **Special Features:**

Operating temperature: -65 to 200 degrees celsius

## **Terminal Type And Quantity:**

4 pin

#### Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

## Fiig:

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